

PJQ4606

30V Complementary Enhancement Mode MOSFET

Current

Voltage

23/-20 A

Features

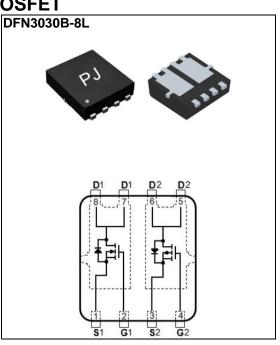
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0

30/-30 V

• Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN3030B-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0008 ounces, 0.022 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	N-CH LIMIT	P-CH LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	-30	Ň	
Gate-Source Voltage		V_{GS}	<u>+</u> 2	V		
Continuous Drain Current (Note 4)	T _C =25°C	l _D	23	-20		
	T _C =100°C		14.5	-12.6	Α	
Pulsed Drain Current (Note 1)	T _C =25°C	I _{DM}	92	-80	1	
Power Dissipation	T _C =25°C	ſ	1	W		
	T _c =100°C	PD	7.			
Continuous Drain Current (Note 4)	T _A =25°C	I _D	7.6	-6.7		
	T _A =70°C		6	-5.3	A	
	T _A =25°C		2		w	
Power Dissipation	T _A =70°C	PD	1.3			
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150		°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	R _{θJC}	7		°C/W	
	Junction to Ambient	R _{θJA}	62.5			
Limited only By Maximum Junction Temperature						



N-CH Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I _D =250uA	30	-	-	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1	1.67	2.5 V	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =8A	-	16	19	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =5A	-	22	28	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	V _{DS} =15V, I _D =8A, V _{GS} =4.5V ^(Note 2,3)	-	4.8	-	nC
Gate-Source Charge	Q _{gs}		-	1.5	-	
Gate-Drain Charge	Q _{gd}		-	2	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1MHZ	-	429	-	pF
Output Capacitance	Coss		-	59	-	
Reverse Transfer Capacitance	Crss		-	47	-	
Turn-On Delay Time	td _(on)	V _{DS} =15V, I _D =1A,	-	6.8	-	
Turn-On Rise Time	t _r	V_{GS} =10V, R_G =6 Ω (Note 2,3)	-	16	-	ns
Turn-Off Delay Time	td _(off)		-	27	-	
Turn-Off Fall Time	t _f		-	7.1	-	
Drain-Source Diode						
Maximum Continuous Drain-Source						
Diode Forward Current	I _S		-	-	23	A
Diode Forward Voltage	V_{SD}	I _S =1A, V _{GS} =0V	-	0.74	1	V



P-CH Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

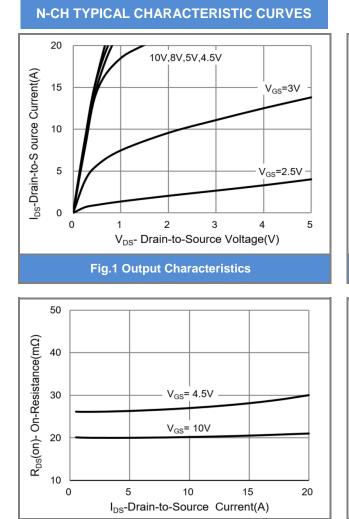
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PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static	[Γ	Г			
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250$ uA	-1	-1.53	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-4A	-	25	30	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-2A	-	36	45	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	V _{DS} =-15V, I _D =-4A, V _{GS} =-4.5V ^(Note 1,2)	-	7.8	-	nC
Gate-Source Charge	Q _{gs}		-	2.7	-	
Gate-Drain Charge	Q _{gd}		-	2.8	-	
Input Capacitance	Ciss	· V _{DS} =-15V, V _{GS} =0V, · f=1MHZ	-	846	-	pF
Output Capacitance	Coss		-	120	-	
Reverse Transfer Capacitance	Crss		-	76	-	
Turn-On Delay Time	td _(on)		-	3.6	-	
Turn-On Rise Time	tr	V_{DS} =-15V, I _D =-1A, V _{GS} =-10V, R _G =6Ω (Note 1,2)	-	23	-	ns
Turn-Off Delay Time	td _(off)		-	90	-	
Turn-Off Fall Time	t _f		-	50	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-20	A
Diode Forward Current	I _S					
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.75	-1	V

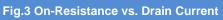
NOTES :

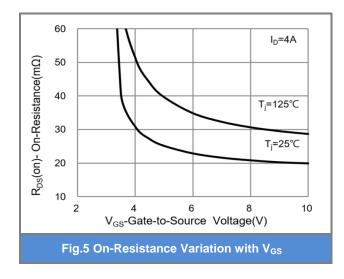
- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{®JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper..
- 6. Guaranteed by design, not subject to production testing.

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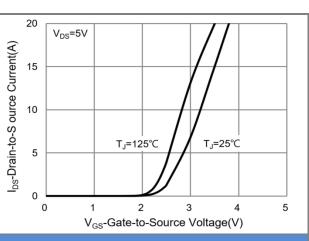


Fig.2 Transfer Characteristics

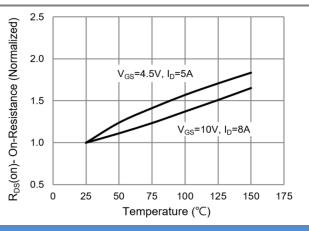
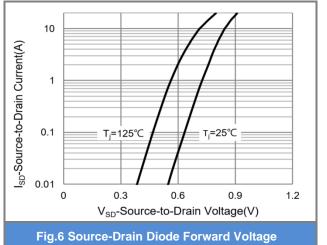


Fig.4 On-Resistance vs. Junction temperature



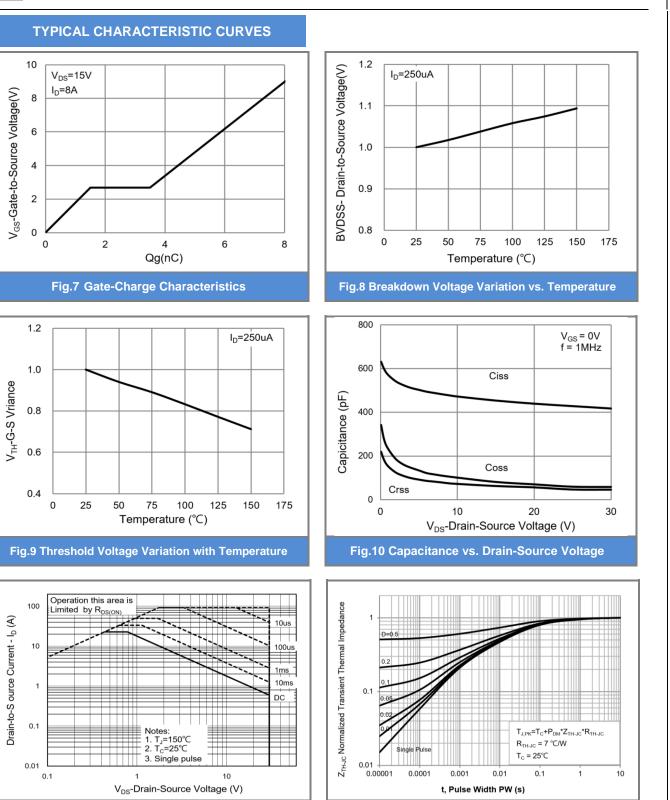
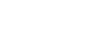


Fig.11 Maximum Safe Operating Area

Fig.12 Normalized Transient Thermal Impedance

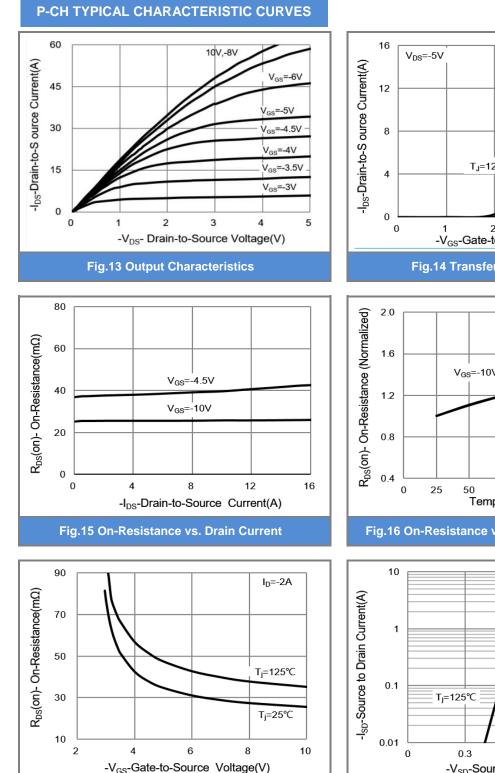


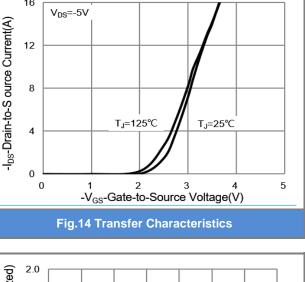
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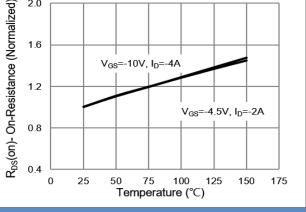


Fig.16 On-Resistance vs. Junction temperature

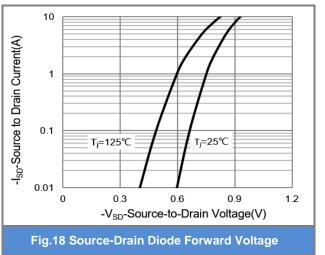
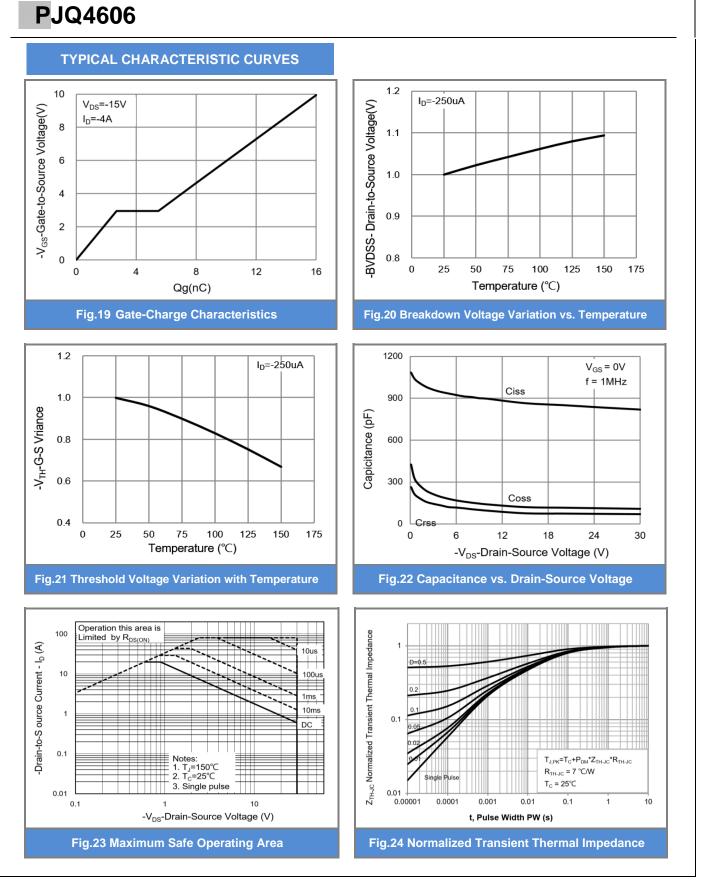


Fig.17 On-Resistance Variation with V_{GS}





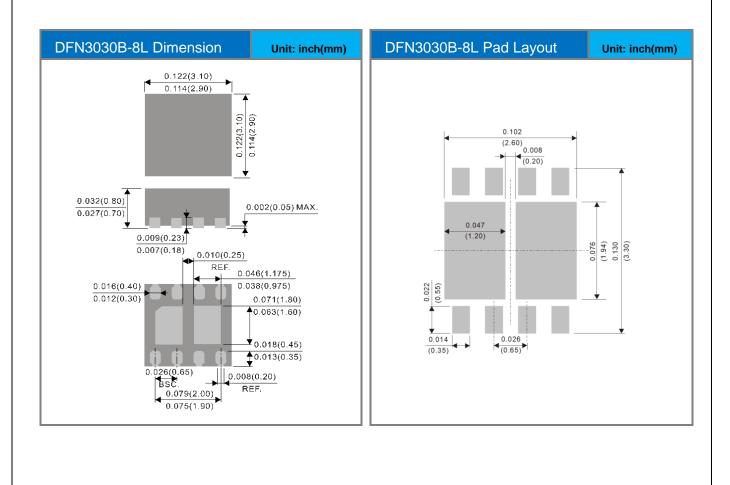




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJQ4606_R1_00001	DFN3030B-8L	3K pcs / 7" reel	4606	Halogen free	

Packaging Information & Mounting Pad Layout





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